

PNP SILICON POWER TRANSISTORS

SJE1497 transistor is designed for use in general purpose Power amplifier, vertical output application

FEATURES:

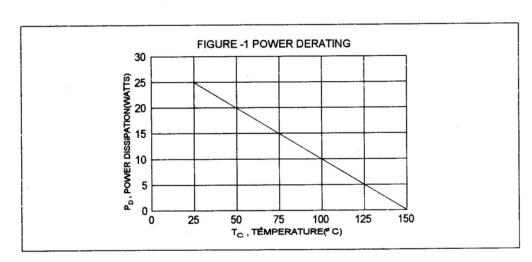
- * Collector-Emitter Voltage V_{CEO}= 150V(Min)
- * DC Current Gain hFE= 30(Min)@I_C= 300mA

MAXIMUM RATINGS

Characteristic	Symbol	SJE1497	Unit
Collector-Emitter Voltage	V _{CEO}	150	V
Collector-Base Voltage	V _{CBO}	200	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current - Continuous - Peak	I _C	1.5 3.0	A
Total Power Dissipation @T _C = 25°C Derate above 25°C	P _D	25 0.2	W/°C
Operating and Storage Junction Temperature Range	T _J ,T _{STG}	-55 to +150	°C

THERMAL CHARACTERISTICS

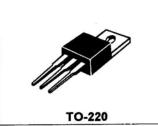
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	Rejc	5.0	°C/W

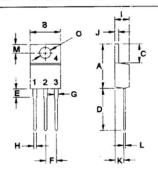


PNP

SJE1497

1.5 AMPERE POWER TRANASISTORS 150 VOLTS 25 WATTS





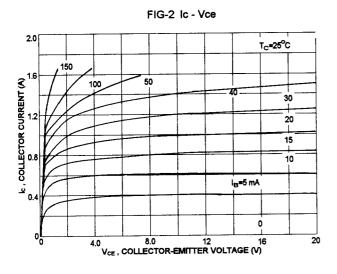
PIN 1.BASE 2.COLLECTOR 3.EMITTER 4.COLLECTOR(CASE)

DIM	MILLIMETERS			
	MIN	MAX		
Α	14.68	16.00		
В	9.78	10.42		
C	5.02	6.60		
D	13.00	14.62		
E	3.10	4.19		
F	2.41	2.67		
G	1.10	1.67		
Н	0.69	1.01		
I	3.21	4.98		
J	1.14	1.40		
K	2.20	3.30		
L	0.28	0.61		
M	2.48	3.00		
0	3.50	4.00		

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characterist	ic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Base Voltage (I _C = 100 uA, I _B = 0)		V _{CBO}	200		V
Collector-Emitter Voltage (I _C = 30 mA, I _B = 0)		V _{CEO}	150		٧
Emitter-Base Voltage (I _B = 1.0 mA, I _C = 0)		V _{EBO}	6.0		٧
Collector Cutoff Current (V _{CB} = 120 V, I _E = 0)		Ісво		10	uA
Emitter Cutoff Current (V _{EB} = 4.0 V, I _C = 0)		IEBO		10	uA
ON CHARACTERISTICS (1)					
DC Current Gain (I _C = 0.3 A, V _{CE} = 5.0 V)		hFE	30		
Collector-Emitter Saturation Voltage (I _C = 1.0 A, I _B = 200 mA)		V _{CE(sat)}		1.0	٧
Base-Emitter On Voltage (I _C = 1.0 A, V _{CE} =10 V)	, , , , , , , , , , , , , , , , , , , ,	V _{BE(on)}		1.5	٧
SWITCHING CHARATERISTICS					•
	V _{CC} = 50 V, I _C = 0.5A I _{B1} = -I _{B2} = 50 mA PW= 20 us	on		0.5	us
Storage Time		ts		1.0	us
Fall Time		tf		0.5	us

⁽¹⁾ Pulse Test: Pulse Width =300 us, Duty Cycle ≦ 2.0%





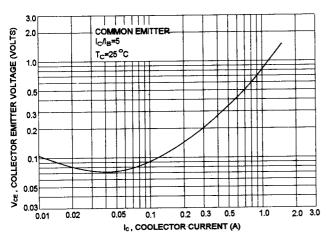
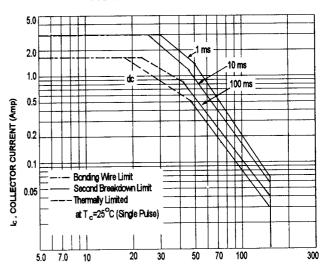


FIG-3 SAFE OPERATING AREA

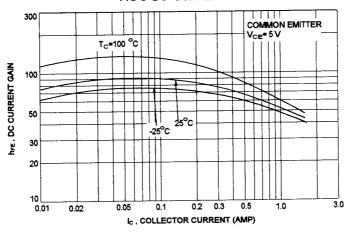


 $\ensuremath{V_{\text{CE}}}$, collector emitter voltage (volts)

There are two limitation on the power handling ability of a transistor:average junction temperature and second breakdown safe operating area curves indicate $I_{\text{C}^{-}}V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of FIG-3 is base on T_{J(PK)}=150 °C;T_C is variable depending on conditions, second breakdown pulse limits are valid for duty cycles to 10% provided T_{J(PK)}≤150°C,At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.







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